

## IR Receiver Modules for Remote Control Systems



19026

### MECHANICAL DATA

#### Pinning:

1 = OUT, 2 = GND, 3 =  $V_S$

### FEATURES

- Very low supply current
- Photo detector and preamplifier in one package
- Internal filter for PCM frequency
- Improved shielding against EMI
- Supply voltage: 2.5 V to 5.5 V
- Improved immunity against ambient light
- Insensitive to supply voltage ripple and noise
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



### DESCRIPTION

The TSOP382.., TSOP384.. series are miniaturized receivers for infrared remote control systems. A PIN diode and a preamplifier are assembled on a lead frame, the epoxy package acts as an IR filter.

The demodulated output signal can be directly decoded by a microprocessor. The TSOP382.. is compatible with all common IR remote control data formats. The TSOP384.. is optimized to suppress almost all spurious pulses from energy saving fluorescent lamps but will also suppress some data signals.

This component has not been qualified according to automotive specifications.

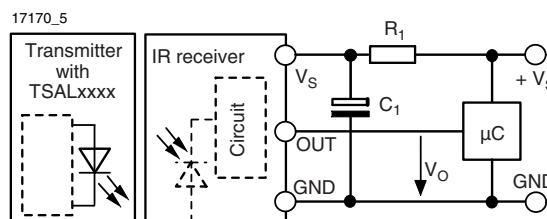
### PARTS TABLE

| CARRIER FREQUENCY | STANDARD APPLICATIONS (AGC2/AGC8) | VERY NOISY ENVIRONMENTS (AGC4) |
|-------------------|-----------------------------------|--------------------------------|
| 30 kHz            | TSOP38230                         | TSOP38430                      |
| 33 kHz            | TSOP38233                         | TSOP38433                      |
| 36 kHz            | TSOP38236                         | TSOP38436                      |
| 38 kHz            | TSOP38238                         | TSOP38438                      |
| 40 kHz            | TSOP38240                         | TSOP38440                      |
| 56 kHz            | TSOP38256                         | TSOP38456                      |

### BLOCK DIAGRAM



### APPLICATION CIRCUIT



$R_1$  and  $C_1$  are recommended for protection against EOS. Components should be in the range of  $33 \Omega < R_1 < 1 \text{ k}\Omega$ ,  $C_1 > 0.1 \mu\text{F}$ .



| ABSOLUTE MAXIMUM RATINGS (1) |                                       |           |                          |      |
|------------------------------|---------------------------------------|-----------|--------------------------|------|
| PARAMETER                    | TEST CONDITION                        | SYMBOL    | VALUE                    | UNIT |
| Supply voltage (pin 3)       |                                       | $V_S$     | - 0.3 to + 6.0           | V    |
| Supply current (pin 3)       |                                       | $I_S$     | 3                        | mA   |
| Output voltage (pin 1)       |                                       | $V_O$     | - 0.3 to ( $V_S + 0.3$ ) | V    |
| Output current (pin 1)       |                                       | $I_O$     | 5                        | mA   |
| Junction temperature         |                                       | $T_j$     | 100                      | °C   |
| Storage temperature range    |                                       | $T_{stg}$ | - 25 to + 85             | °C   |
| Operating temperature range  |                                       | $T_{amb}$ | - 25 to + 85             | °C   |
| Power consumption            | $T_{amb} \leq 85 \text{ °C}$          | $P_{tot}$ | 10                       | mW   |
| Soldering temperature        | $t \leq 10 \text{ s, 1 mm from case}$ | $T_{sd}$  | 260                      | °C   |

**Note**

(1) Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect the device reliability.

| ELECTRICAL AND OPTICAL CHARACTERISTICS (1) |  |                    |      |          |      |                 |
|--|--|--------------------|------|----------|------|-----------------|
| PARAMETER                                  | TEST CONDITION   | SYMBOL             | MIN. | TYP.     | MAX. | UNIT            |
| Supply current (pin 3)                     | $E_v = 0, V_S = 3.3 \text{ V}$   | $I_{SD}$           | 0.27 | 0.35     | 0.45 | mA              |
|  | $E_v = 40 \text{ klx, sunlight}$   | $I_{SH}$           |      | 0.45     |      | mA              |
| Supply voltage                             |  | $V_S$              | 2.5  |          | 5.5  | V               |
| Transmission distance                      | $E_v = 0$ , test signal see fig. 1, IR diode TSAL6200, $I_F = 250 \text{ mA}$              | $d$                |      | 45       |      | m               |
| Output voltage low (pin 1)                 | $I_{OSL} = 0.5 \text{ mA, } E_e = 0.7 \text{ mW/m}^2$ , test signal see fig. 1             | $V_{OSL}$          |      |          | 100  | mV              |
| Minimum irradiance                         | Pulse width tolerance: $t_{pi} - 5/f_0 < t_{po} < t_{pi} + 6/f_0$ , test signal see fig. 1 | $E_e \text{ min.}$ |      | 0.15     | 0.35 | $\text{mW/m}^2$ |
| Maximum irradiance                         | $t_{pi} - 5/f_0 < t_{po} < t_{pi} + 6/f_0$ , test signal see fig. 1                        | $E_e \text{ max.}$ | 30   |          |      | $\text{W/m}^2$  |
| Directivity                                | Angle of half transmission distance  | $\phi_{1/2}$       |      | $\pm 45$ |      | deg             |

**Note**

(1)  $T_{amb} = 25 \text{ °C}$ , unless otherwise specified

**TYPICAL CHARACTERISTICS**

$T_{amb} = 25 \text{ °C}$ , unless otherwise specified

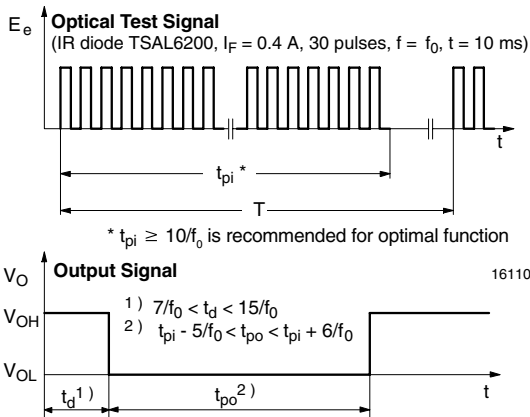


Fig. 1 - Output Active Low

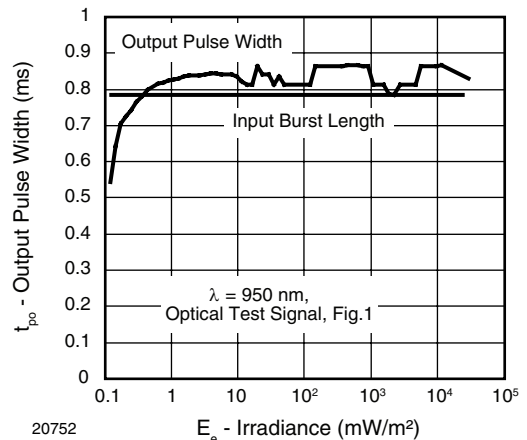


Fig. 2 - Pulse Length and Sensitivity in Dark Ambient



Fig. 3 - Output Function



20757

Fig. 6 - Sensitivity in Bright Ambient



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Fig. 4 - Output Pulse Diagram



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Fig. 7 - Sensitivity vs. Supply Voltage Disturbances



16925

Fig. 5 - Frequency Dependence of Responsivity



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Fig. 8 - Sensitivity vs. Electric Field Disturbances

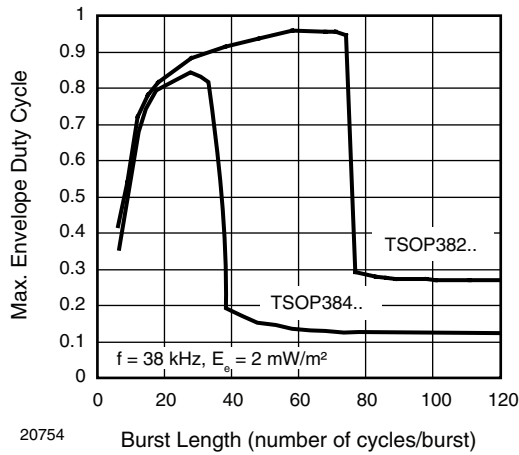


Fig. 9 - Max. Envelope Duty Cycle vs. Burst Length

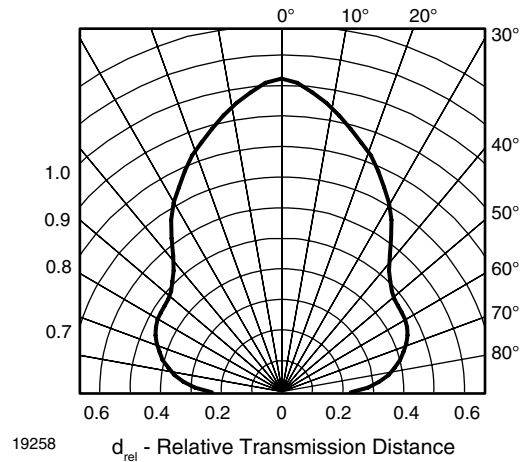


Fig. 12 - Horizontal Directivity

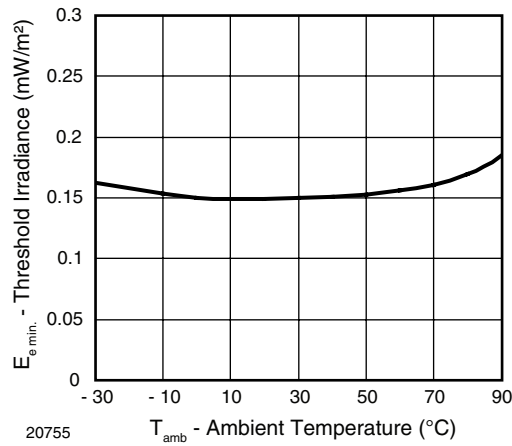


Fig. 10 - Sensitivity vs. Ambient Temperature

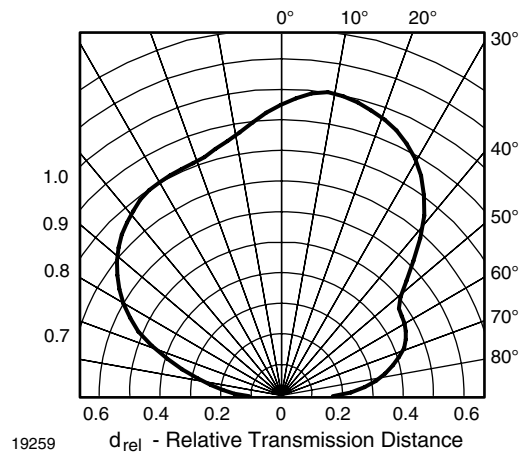


Fig. 13 - Vertical Directivity

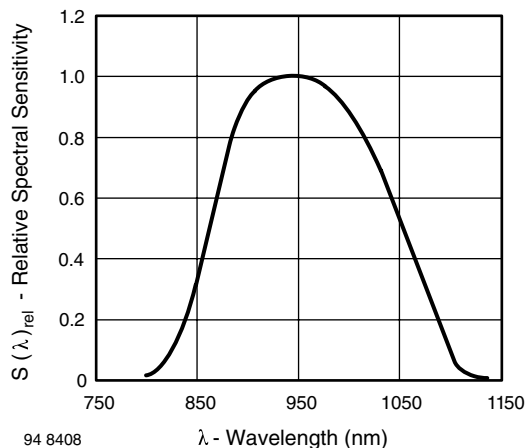


Fig. 11 - Relative Spectral Sensitivity vs. Wavelength

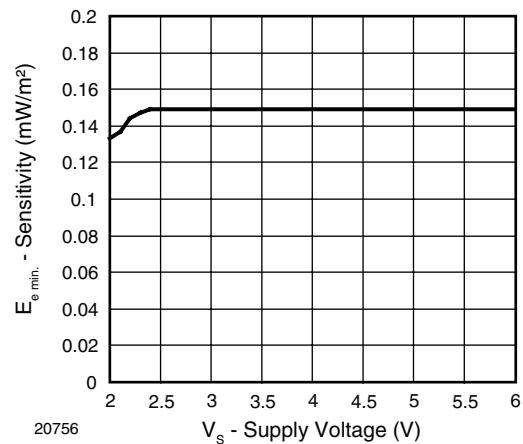


Fig. 14 - Sensitivity vs. Supply Voltage

## SUITABLE DATA FORMAT

The TSOP382.., TSOP384.. series are designed to suppress spurious output pulses due to noise or disturbance signals. Data and disturbance signals can be distinguished by the devices according to carrier frequency, burst length and envelope duty cycle. The data signal should be close to the band-pass center frequency (e.g. 38 kHz) and fulfill the conditions in the table below.

When a data signal is applied to the TSOP382.., TSOP384.. in the presence of a disturbance signal, the sensitivity of the receiver is reduced to insure that no spurious pulses are present at the output. Some examples of disturbance signals which are suppressed are:

- DC light (e.g. from tungsten bulb or sunlight)
- Continuous signals at any frequency
- Strongly or weakly modulated noise from fluorescent lamps with electronic ballasts (see figure 15 or figure 16)



Fig. 15 - IR Signal from Fluorescent Lamp with Low Modulation



Fig. 16 - IR Signal from Fluorescent Lamp with High Modulation

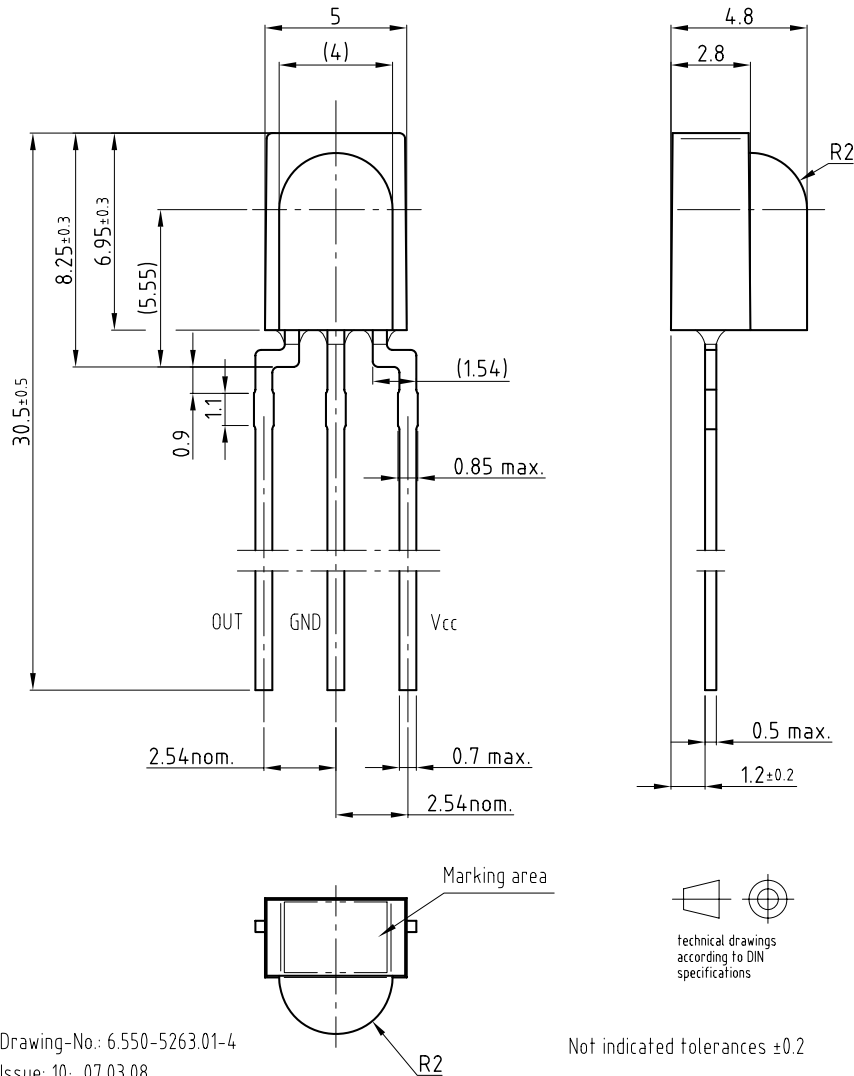
|  | TSOP382..                                      | TSOP384..                                       |
|--|--|---|
| Minimum burst length   | 10 cycles/burst                                | 10 cycles/burst                                 |
| After each burst of length a minimum gap time is required of               | 10 to 70 cycles<br>≥ 10 cycles                 | 10 to 35 cycles<br>≥ 10 cycles                  |
| For bursts greater than a minimum gap time in the data stream is needed of | 70 cycles<br>> 4 x burst length                | 35 cycles<br>> 10 x burst length                |
| Maximum number of continuous short bursts/second                           | 1800   | 1500  |
| Compatible to NEC code   | yes  | yes   |
| Compatible to RC5/RC6 code   | yes  | yes   |
| Compatible to Sony code  | yes  | no  |
| Compatible to Thomson 56 kHz code  | yes  | yes   |
| Compatible to Mitsubishi code (38 kHz, preburst 8 ms, 16 bit)              | yes  | no  |
| Compatible to Sharp code   | yes  | yes   |
| Suppression of interference from fluorescent lamps                         | Most common disturbance signals are suppressed | Even extreme disturbance signals are suppressed |

### Note

For data formats with short bursts please see the datasheet for TSOP381.., TSOP383..



PACKAGE DIMENSIONS in millimeters



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Issue: 10; 07.03.08  
19009

Not indicated tolerances  $\pm 0.2$

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